

# isc N-Channel MOSFET Transistor

## IXTP7N60P

#### FEATURES

- Static drain-source on-resistance: R<sub>DS</sub>(on) ≤ 1.1Ω@V<sub>GS</sub>=10V
- Fully characterized avalanche voltage and current
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



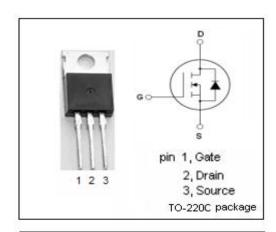
- DC/DC Converter
- · Ideal for high-frequency switching and synchronous rectification

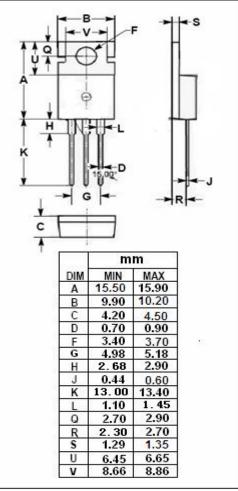
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage 6		V	
V <sub>GS</sub>	Gate-Source Voltage	±30	V	
I <sub>D</sub>	Drain Current-Continuous 7		А	
I <sub>DM</sub>	Drain Current-Single Pulsed 14		А	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C 150		W	
Tj	Operating Junction Temperature	-55~150	$^{\circ}\mathbb{C}$	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{\text{th(j-c)}}$	Junction-to-case thermal resistance	0.83	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	600		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 100 μ A	3.0	5.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 3.5A		1.1	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		5	- μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 125°C		50	
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 7A; V <sub>GS</sub> = 0V		1.5	V



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